

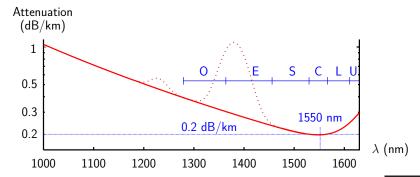


### **Optical amplifiers**





- High-speed wired communications: optical fibers
- Primary limiting factor: attenuation







Avoid signal regenerators (O-E-O bulky; all-optical not mature)

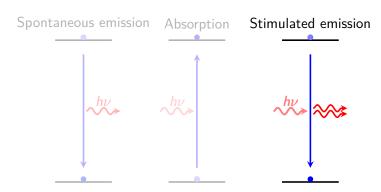
### ⇒ Optical amplifiers

- since 1993: long-distance transmissions
- 2000s: metropolitan networks
- now: extended-range access networks
- envisioned: all-optical signal processing
- ⇒ Transmission bandwidth = amplifiers' gain bandwidth





Optical amplification based on stimulated emission:



Need more electrons in excited state than in fundamental state

⇒ population inversion







- Fundamental parameters:
  - $\lambda$ , bandwidth
  - Gain, saturation / output power
- System / technological parameters:
  - Noise, signal distortion
  - Speed, transient management
  - Packaging, bulkiness, consumption
  - Cost
- Extra functionalities:
  - Dispersion compensation
  - Channel add/drop
  - Monitoring

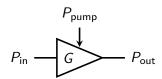




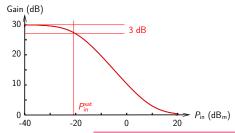
# Gain and saturation

■ Gain:

$$P_{
m out} = G P_{
m in}$$
  $P_{
m in} \left( G - 1 
ight) < P_{
m pump}$ 



■ Saturation / max. output power







- Amplifiers add noise (else violate uncertainty principle)
  - Amplified spontaneous emission (ASE)
  - Noise transfer from pump
  - Vacuum fluctuations

Noise Figure:

$$\textit{NF} = \frac{\mathsf{SNR}_{\mathsf{in}}}{\mathsf{SNR}_{\mathsf{out}}} \quad \text{assuming quantum-noise-limited input signal}$$

$$NF \geqslant 3 \, dB$$
 (for a high-gain optical amplifier)







## Noise from a chain of amplifiers

Amplifier chain: the first amplifier's noise dominates



$$NF = NF_1 + \frac{NF_2 - 1}{G_1} + \frac{NF_3 - 1}{G_1G_2} + \dots$$
 (Friis formula)

(Not to confuse with transmission chain, which has strong attenuation between amplifiers)

- Attenuation: quantum noise not affected
  - $\Rightarrow$  *NF*(attenuator) = attenuation
- Insertion loss: attenuation at amplifier input
  - ⇒ Strong influence on NF







- Dispersion (chromatic and polarization) in long amplifiers
- Polarization-dependent gain (PDG)
- High power ⇒ non-linearity
  - WDM ⇒four-wave mixing, crosstalk
  - Soliton-like pulse compression
- Gain saturation rapidity
  - Fast gain ⇒ non-linearity, distorted bits
  - Slow gain ⇒ modulation-transparent, problems with transients





### Pumping types

- electrical ⇒ easy integration
- optical ⇒ must insert pump, separate signal at output

### Packaging

- all-integrated / discrete components
- rackable units
- bulkiness, electrical consumption
- submarine cables: fit in cable, remote power supply...

#### Integration

- photoreceiver + preamplifier
- loss-less splitter
- active switching matrix









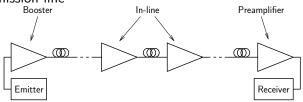
- WDM amplification
  - Simultaneous amplification of  $\lambda$  comb
  - Gain equalization
- Gain control
  - Gain variation rapidity
  - Input power fluctuation handling
- Inter-stage access
  - Dispersion compensation
  - ROADM: channel add-drop
- Monitoring
  - Check operation
  - Optical power of individual  $\lambda$  channels
  - Channel estimation



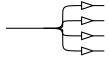


# **選擇 Typical usage configurations**

Transmission line



- ... in a mesh network
  - Different channels → different paths
  - Variable traffic, packet network ⇒ power fluctuations
  - Reconfigurable channel add-drop (ROADM)
- "Loss-less" splitter:  $1 \times N$  + integrated amplifiers







# Needs for different usages

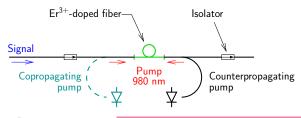
	Transmission			Network	
	Booster	In-line	Preamp	Metro	Access
High gain	important	critical	critical		
High P <sub>out</sub>	critical	important			
Low NF and insertion loss		important	critical		
Polarization independence	important	critical	critical	critical	critical
Bandwidth		wide	narrow		Coarse WDM
Dispersion mgmt		DCF		multi-span	
Add/drop				ROADM	
Low consumpt		important			important
Low cost				important	critical



# Erbium-doped fiber amplifiers

### Currently most-used amplifiers: EDFAs

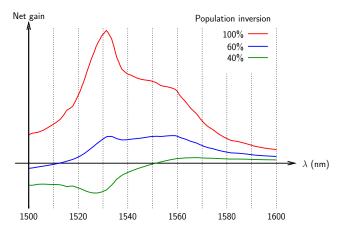
- Er<sup>3+</sup> ions in silica (glass) fiber (codoped Al<sub>2</sub>O<sub>3</sub>, GeO<sub>2</sub>, P<sub>2</sub>O<sub>5</sub>... possibly TeO<sub>2</sub> ou ZBLAN/fluoride  $\rightarrow$  stronger doping)
- Optical pumping: 980 nm, used to be 1480 nm, more efficient before good 980-nm lasers
- Amplification in C-band (1530-1565 nm) or L-band (1565-1600 nm)
- Setup:







# **EDFA**: gain spectrum



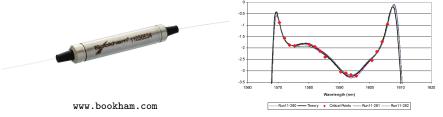
- Adjustement: pump power and  $\lambda$ , fiber length...
- Special-glass fibers (TeO<sub>2</sub>, ZBLAN)
- Gain-flattening filters (GFFs)





# Gain-flattening filters

### Gain-flattening filters $\rightarrow$ gain equalization



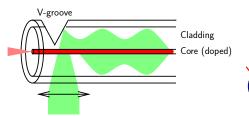
- Interference filters or Fiber Bragg gratings (FBGs)
- Complex design
- Sensitive → temperature variations
  - Active temperature control
  - Athermic packaging that compensates dilatation
- Insertion loss
  - $\Rightarrow$  Between stages (before input: NF  $\nearrow$ , after output:  $P_{out} \searrow$ )





# **選載 EDFA**: pumping

- Single-mode fiber required for the signal
  - ⇒ low numerical aperture ⇒coupling losses when injecting
- Single-mode not needed for pump
  - ⇒ double-cladding fiber, V-groove injection (high-power amplifiers)















### 

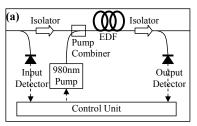
- C- or L-band
- All-fiber ⇒ low insertion loss
- Gain up to 40 dB,  $P_{\text{out}} > 23 \, \text{dB}_{\text{m}}$ , polarization-independent
- NF down to  $\sim$  3 dB (lab) ; 4–6 dB in practice
- Long-lifetime excited states (few ms)
  - ⇒ gain = constant over each bit
  - ⇒ good linearity
- Drawbacks:
  - Optical pumping ⇒ complex
  - Sensitive to traffic fluctuations (on packet networks)





### Modern EDFAs

- Usage: all applications on C + L bands
- Dynamic gain equalization
- Power monitoring (not on individual WDM channels: too costly)
- 2+ stages, mid-point access  $\rightarrow$  DCF, add-drop



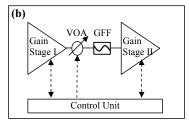
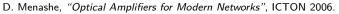


Figure 1. (a) Basic Single Stage Amplifier Module, (b) Broadband Variable Gain EDFA.



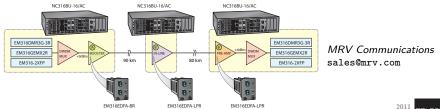




# EDFA packaging









### Same principle as EDFAs:

- EDWA: doped waveguide instead of fiber
  - Short length (few cm), low bulk
  - ullet Obsoleted by mini-EDFAs (fiber spool fits < 10 cm)
- EYDFA : codoping erbium-ytterbium
  - High output power (30–45 dB<sub>m</sub>)
  - Only part of C band (1540–1560 nm)
- Thulium amplifier (lab)
  - Tm<sup>3+</sup> ions in fluoride glass
  - S-band amplification
    - (Depending on pump: 700 nm, 800 nm, 1  $\mu$ m, 1.4  $\mu$ m, and/or 1.56  $\mu$ m)
- Short- $\lambda$  amplifiers (lab)
  - $\hbox{ \bf Praseodymium or neodymium} \to \hbox{ O-band}$
  - Ytterbium  $ightarrow \lambda \sim 1 \, \mu m$

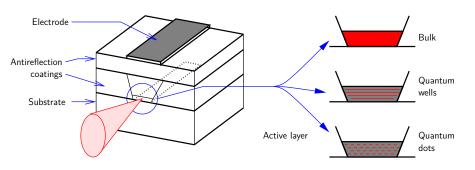




# Semiconductor optical amplifiers

SOA = semiconductor laser without cavity

→ Fabry-Perot laser + antireflection-coated facets

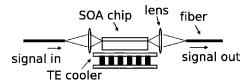






#### SOA module:

- chip mounted on base
- bias current 200 mA − 2 A (according to active layer volume)
- lacktriangle Peltier thermoelectric module o cooling, temperature control
- lensed fibers or microlenses



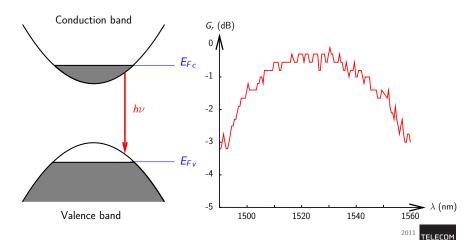
L. Spiekman, "Semiconductor optical amplifiers for reconfigurable optical networks", J. Optical Networking 6 (11), Nov 2007.





### **图图** SOA characteristics

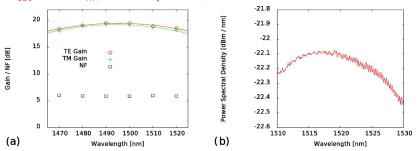
### Gain determined by energy band structure





### Bulk / quantum-well (QW) SOAs:

- Mature technology, same wavelengths as lasers
- $\blacksquare$   $G \sim 20 \, \mathrm{dB}$ , BW  $> 50 \, \mathrm{nm}$ , NF  $\sim 6 \, \mathrm{dB}$
- Low polarization dependency, low ripple
- $P_{\mathsf{sat}} < 20\,\mathsf{dB_m}$ ,  $\tau \sim 100\,\mathsf{ps-}1\,\mathsf{ns}$ ; nonlinearities



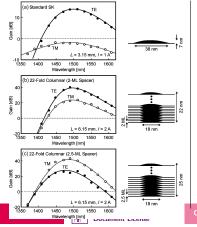
L. Spiekman, "Semiconductor optical amplifiers for reconfigurable optical networks", J. Optical Networking 6 (11), Nov 2007.

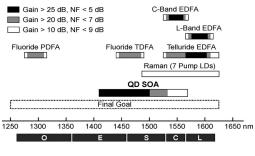


# Quantum-dot SOAs

### Quantum-dot (QD) SOAs:

- $\blacksquare$   $G\sim 10$ –25 dB, BW  $\sim 100$  nm,  $au\sim$  few ps
- Excellent linearity
- Development underway; almost mature → C-band





T. Akiyama et al., "Quantum-Dot Semiconductor Optical Amplifiers", Proc. IEEE 95 (9), Sept 2007.

Cédric Ware <cedric.ware@telecom-paristech.fr>





### Historically, SOA problems:

■ SOA fast  $(\sim 1 \text{ ns}) \Rightarrow \text{bit-timescale signal distortions}$ 

NRZ signal NRZ signal through SOA

- Nonlinearities, four-wave mixing ⇒ problem with WDM
- EDFA preferred, except:
  - Niche: transmissions outside C-band
  - Niche: integrated amplifiers (e. g. with photodiode)
  - Active MZI gates
  - Signal processing:  $\lambda$  conversion, regeneration...







### Currently, SOAs making a comeback:

- Long-distance transmissions changing techniques
  - Constant-envelope modulations (NRZ-xPSK)
  - Packet networks ⇒ transients on packet timescales
- Development of novel metro+access networks
  - Low cost preferred
  - Coarse WDM ⇒ less FWM, need wide bandwidth
  - Shorter distances/lower powers  $\Rightarrow$  small signals  $\Rightarrow$  SOAs  $\sim$  linear
  - "Extender-boxes" → long-range access networks (> 20 km)







- Quantum-dot SOAs:
  - Very wide bandwidth
  - Ultrafast electron transitions + wetting layer ⇒ gain is clamped
- LOA: SOA + VCSEL
  - Active layer sandwiched between Bragg reflectors
  - Laser perpendicular to signal propagation
  - Clamps carrier density  $\Rightarrow$  better linearity





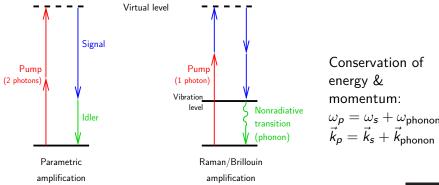
- "Novel functionalities" of the 1990s (nonlinear effects)
  - All-optical signal processing
  - Wavelength conversion
  - Modulation format conversion
  - Regeneration
  - Logic gates
  - → Still not widespread outside labs
- Integration / use as on-off switch
  - Loss-less splitters
  - Switching matrices
  - RSOAs: replaces laser + modulator for wavelength-independent optical network units in access networks





# Nonlinear effects (for amplification)

- Several-photon interactions
- Interactions with non-electronic energy levels: phonons

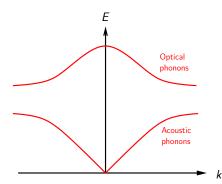


2011



# Phonon types

- Acoustic phonons: lattice vibrations, low frequencies
  - → Brillouin effect
- Optical phonons: molecular vibrations, high frequencies
  - $\rightarrow$  Raman effect.



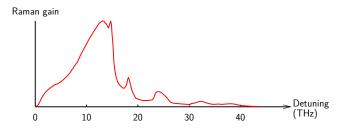
## Brillouin scattering

- Phase matching:  $k_{phonon} \propto \omega_{phonon}$  thus, for significant frequency difference (hence gain), need large  $k_{\rm phonon}$ .
- $\Rightarrow$  counterpropagating pump  $(-k_p = k_s k'_{phonon})$ .
  - Very narrow bandwidth: few 10 MHz.
- ⇒ Application: possibly low-bitrate WDM demultiplexing.
- → Mostly, parasitic effect that limits optical power.



# **光**配 Raman amplification

Raman-effect fiber amplifier (RFA): same setup as EDFA, but the "active" fiber is a standard, long fiber, and  $\lambda_{pump}$  chosen as a function of  $\lambda_{signal}$ .



Gain peak:  $\Delta \nu \sim 12\,\text{THz}$  ( $\Delta \lambda \sim 100\,\text{nm}$ ).



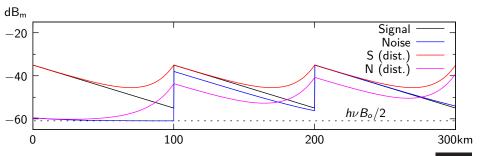
- Phase matching:  $k_{phonon}$  may be large or small compared to  $k_{ont}$  for similar frequencies, so pumping can be copropagating  $(k_p = k_s + k_{phonon})$  or counterpropagating  $(-k_p = k_s - k'_{phonon})$
- But: very fast effect  $\Rightarrow$  transfers pump noise to signal
- If counterpropagating pump, noise ends up averaged over each bit
- ⇒ Counterpropagating pump





# Raman amplifier = distributed amplification

- Localized amplifiers: between fiber spans
- Distributed amplifiers: gain along tail of transmission
- less attenuation noise, better overall noise figure.







#### Pros:

- Works at any  $\lambda$
- Distributed amplification  $\Rightarrow$  better NF
- Dual pumping  $\Rightarrow$  gain over whole transmission span

### Cons:

- Non-uniform gain
  - → Multiple pumps
- Need long fiber for significant gain
  - ⇒ directly over transmission fiber
- Usage: in-line amplification.

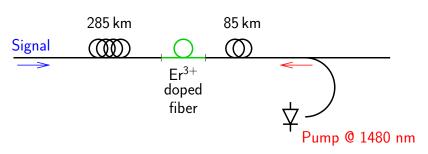




# Hybrid Raman–EDFA amplification

Pump  $\sim 1460$ –1480 nm, standard + doped fibers: C-band EDFA + Raman

 $\Rightarrow$  2.5 Gbps over 370 km with single amplifier stage







### Current usages:

- EDFAs mature → all telecom applications
  - installed in  $\sim$  all amplified networks
  - only C and L bands; require control → transients
- Raman  $\rightarrow$  long-range transmissions
  - deployed in recent systems
- SOA  $\rightarrow$  low cost
  - beginning to be used

#### Under development:

- SOA  $\rightarrow$  special functions (RSOAs; all-optical processing)
- QD-SOA: very promising
  - catch up with EDFA when available in C band?

### Research or non-telecom usages:

■ EYDFA (high power); Tm, Pr, Yb ( $\lambda$  < 1500 nm)







- E. Desurvire, "Erbium-Doped Fiber Amplifiers, Device and System Developments", Wiley-Interscience, 2002.
- D. Menashe, "Optical Amplifiers for Modern Networks", ICTON 2006.
- L. Spiekman, "Semiconductor optical amplifiers for reconfigurable optical networks", J.
   Optical Networking 6 (11), Nov 2007.
- T. Akiyama et al., "Quantum-Dot Semiconductor Optical Amplifiers", Proc. IEEE 95 (9), Sept 2007.
- C. Headley, G. P. Agrawal, "Raman amplification in fiber optical communication systems", Elsevier Academic Press, 2005.
- S. Jiang et al., "Full characterization of modern transmission fibers for Raman amplified-based communication systems", Optics Express 15 (8), Apr 2007.









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